NSN 5962-01-246-6483

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Body Length:	
0.808 inches	
Body Width:	
0.294 inches	
Body Height:	
0.204 inches	
Maximum Power Dissipati	on Rating:
1.0 watts	
Operating Tempurature R	ange:
-55.0/+125.0 degrees celsiu	s
Storage Tempurature Ran	ge:
-65.0/+150.0 degrees celsiu	s
Features Provided:	
Hermetically sealed and but	n in and programmable and bipolar and w/enable and w/buffered output
Inclosure Material:	
Ceramic	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
6 input	
Terminal Surface Treatme	nt:
Solder	
Voltage Rating And Type	Per Characteristic:
7.0 volts power source	
Time Rating Per Chacteris	stic:
50.00 nanoseconds propaç	ation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Type:	
Rom	
Memory Capacity:	
Unknown	
Test Data Document:	
96906-mil-std-883 standard	(includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quant	ity:
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	

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- Demilitarization:
- Yes demil/mli

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